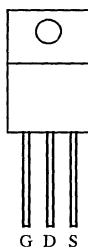


N-Channel Enhancement-Mode Transistor

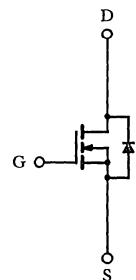
Product Summary

| $V_{(BR)DSS}$ (V) | $r_{DS(on)}$ (Ω) | I_D (A) |
|-------------------|---------------------------|-----------|
| 200 | 0.16 | 14 |

TO-257AB
Hermetic Package

Case Isolated

Top View



N-Channel MOSFET

Absolute Maximum Ratings ($T_C = 25^\circ\text{C}$ Unless Otherwise Noted)

| Parameter | Symbol | Limit | Unit |
|--|----------------|------------|------|
| Drain-Source Voltage | V_{DS} | 200 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | |
| Continuous Drain Current ($T_J = 150^\circ\text{C}$) | I_D | 14 | A |
| | | 8.5 | |
| Pulsed Drain Current | I_{DM} | 56 | W |
| Maximum Power Dissipation | P_D | 60 | |
| | | 23 | |
| Operating Junction and Storage Temperature Range | T_J, T_{stg} | -55 to 150 | °C |
| Lead Temperature ($1/16$ " from case for 10 sec.) | T_L | 300 | |

6

N-/P-Channel
MOSFETs

Thermal Resistance Ratings

| Parameter | Symbol | Typical | Maximum | Unit |
|-----------------------------|------------|---------|---------|------|
| Maximum Junction-to-Ambient | R_{thJA} | | 80 | °C/W |
| Maximum Junction-to-Case | R_{thJC} | | 2.1 | |
| Case-to-Sink | R_{thCS} | 1.0 | | |

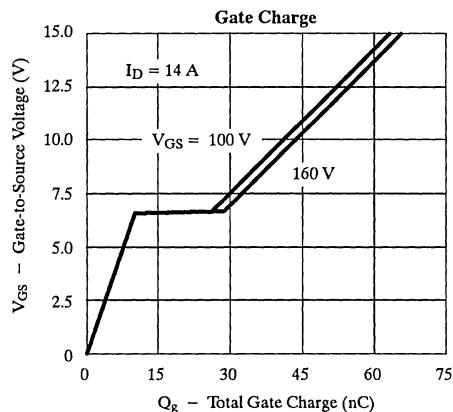
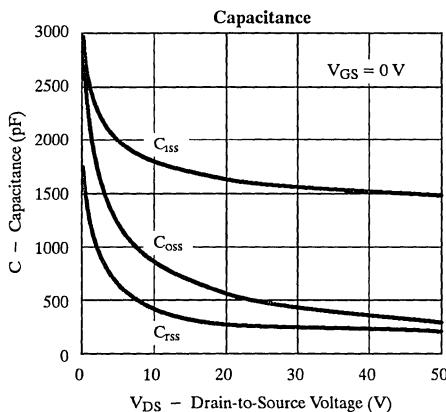
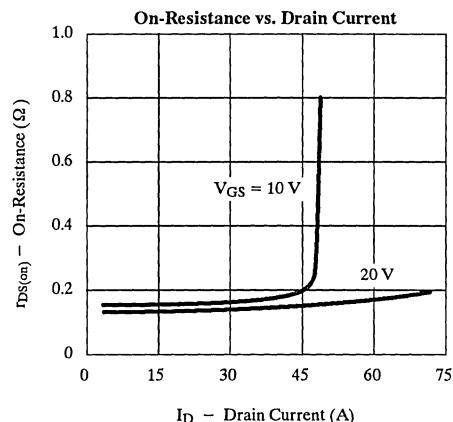
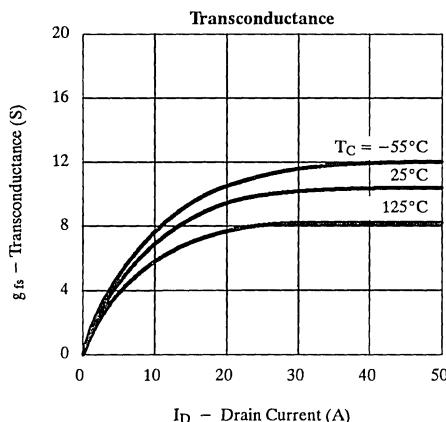
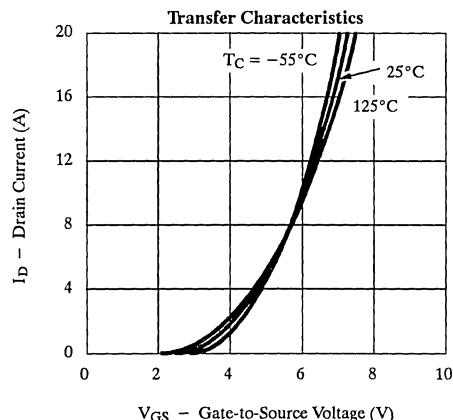
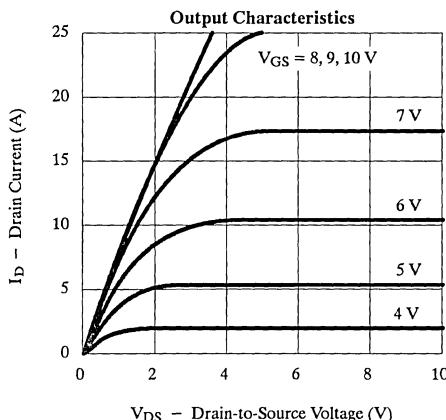
Specifications ($T_J = 25^\circ\text{C}$ Unless Otherwise Noted)

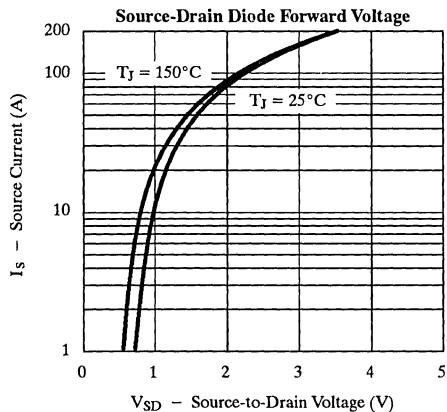
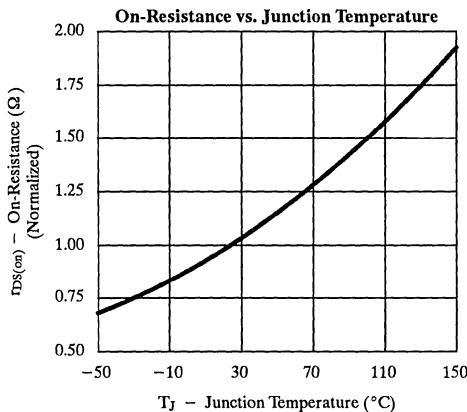
| Parameter | Symbol | Test Condition | Limit | | | Unit |
|---|-----------------------------|---|-------|------------------|-----------|---------------|
| | | | Min | Typ ^a | Max | |
| Static | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(\text{BR})\text{DSS}}$ | $V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$ | 200 | | | V |
| Gate Threshold Voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$ | 2.0 | | 4.0 | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 160 \text{ V}, V_{GS} = 0 \text{ V}$ | | | 25 | μA |
| | | $V_{DS} = 160 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 125^\circ\text{C}$ | | | 250 | |
| On-State Drain Current ^b | $I_{D(\text{on})}$ | $V_{DS} = 10 \text{ V}, V_{GS} = 10 \text{ V}$ | 14 | | | A |
| Drain-Source On-State Resistance ^b | $r_{DS(\text{on})}$ | $V_{GS} = 10 \text{ V}, I_D = 8.5 \text{ A}$ | | 0.14 | 0.16 | Ω |
| | | $V_{GS} = 10 \text{ V}, I_D = 8.5 \text{ A}, T_J = 125^\circ\text{C}$ | | 0.25 | 0.30 | |
| Forward Transconductance ^b | g_{fs} | $V_{DS} = 15 \text{ V}, I_D = 8.5 \text{ A}$ | 5.0 | | | S |
| Dynamic | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$ | | 1550 | | pF |
| Output Capacitance | C_{oss} | | | 500 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 220 | | |
| Total Gate Charge ^c | Q_g | $V_{DS} = 100 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 14 \text{ A}$ $V_{DD} = 100 \text{ V}, R_L = 7.1 \Omega$ $I_D \approx 14 \text{ A}, V_{GEN} = 10 \text{ V}, R_G = 4.7 \Omega$ | | 44 | 77 | nC |
| Gate-Source Charge ^c | Q_{gs} | | | 10 | 15 | |
| Gate-Drain Charge ^c | Q_{gd} | | | 26 | 35 | |
| Turn-On Delay Time ^c | $t_{d(on)}$ | | | 10 | 30 | ns |
| Rise Time ^c | t_r | | | 60 | 100 | |
| Turn-Off Delay Time ^c | $t_{d(off)}$ | $I_F = 14 \text{ A}, di/dt = 100 \text{ A}/\mu\text{s}$ | | 30 | 80 | ns |
| Fall Time ^c | t_f | | | 40 | 95 | |
| Source-Drain Diode Ratings and Characteristics | | | | | | |
| Continuous Current | I_S | | | | 14 | A |
| Pulsed Current | I_{SM} | | | | 56 | |
| Diode Forward Voltage ^b | V_{SD} | $I_F = 14 \text{ A}, V_{GS} = 0 \text{ V}$ | | | 2.0 | V |
| Reverse Recovery Time | t_{rr} | $I_F = 14 \text{ A}, di/dt = 100 \text{ A}/\mu\text{s}$ | | 150 | 650 | μC |
| Reverse Recovery Charge | Q_{rr} | | | 0.5 | | |

Notes:

- a. For design aid only; not subject to production testing.
- b. Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$.
- c. Independent of operating temperature.

Typical Characteristics (25°C Unless Otherwise Noted)



2N7086**Typical Characteristics (25°C Unless Otherwise Noted)****Thermal Ratings**